

500 mA, 50 V PNP resistor-equipped transistors

Rev. 1 — 13 May 2014

**Product data sheet** 

### 1. Product profile

### 1.1 General description

PNP Resistor-Equipped Transistor (RET) family in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

#### Table 1. Product overview

Type number	Package	•			Package	
	Nexperia	JEITA	JEDEC	complement	configuration	
PDTB143ET	SOT23	TO-236AB	-	PDTD143ET	small	
PDTB143XT				PDTD143XT		
PDTB114ET				PDTD114ET		

#### 1.2 Features

- 500 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count

### **1.3 Applications**

- IC inputs control
- Cost-saving alternative to BC807 or BC817 series transistors in digital applications

- ± 10 % resistor ratio tolerance
- AEC-Q101 qualified
- High temperature applications up to 175 °C
- Switching loads



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### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-50	V
lo	output current		-	-	-500	mA
R1	bias resistor 1 (input)				<b>I</b>	
	PDTB143ET			4.7		kΩ
	PDTB143XT			4.7		kΩ
	PDTB114ET			10		kΩ
R2	bias resistor 2 (base-emitter)				<b>I</b>	
	PDTB143ET			4.7		kΩ
	PDTB143XT			10		kΩ
	PDTB114ET			10		kΩ

## 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	input (base)		
2	GND (emitter)		3
3	output (collector)		1 R1 R2 2 sym003

### 3. Ordering information

#### Table 4.Ordering information

Type number	Package		
	Name	Description	Version
PDTB1xxxT series	TO-236AB	plastic surface-mounted package; 3 leads	SOT23

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### 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
PDTB143ET	*4X
PDTB143XT	*4Y
PDTB114ET	*09

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

#### Table 6. Limiting values

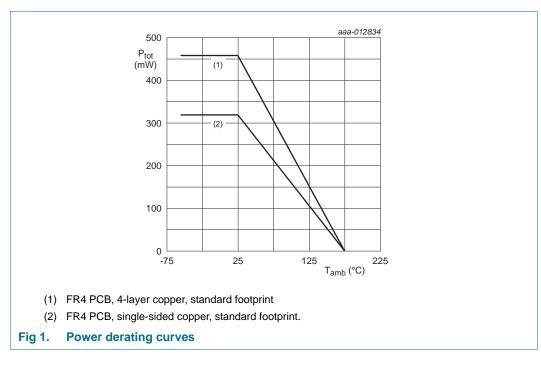
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-50	V
V <sub>EBO</sub> emitter-base voltage		open collector				
	PDTB143ET			-	-10	V
	PDTB143XT			-	-7	V
	PDTB114ET			-	-10	V
VI	input voltage					
	PDTB143ET			-30	+10	V
	PDTB143XT			-30	+7	V
	PDTB114ET			-50	+10	V
lo	output current			-	-500	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u>	-	320	mW
			[2]	-	460	mW
Tj	junction temperature			-	175	°C
T <sub>amb</sub>	ambient temperature			-55	+175	°C
T <sub>stg</sub>	storage temperature			-55	+175	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

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### 6. Thermal characteristics

#### Table 7.Thermal characteristics

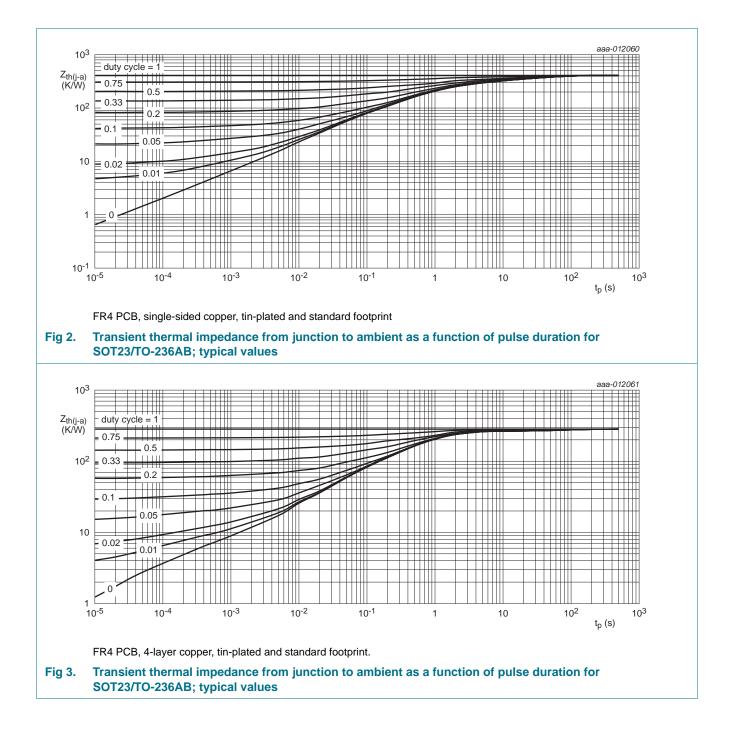
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction	in free air	[1]	-	-	470	K/W
	to ambient		[2]	-	-	327	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

# **PDTB1xxxT series**

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PDTB1XXXT SER

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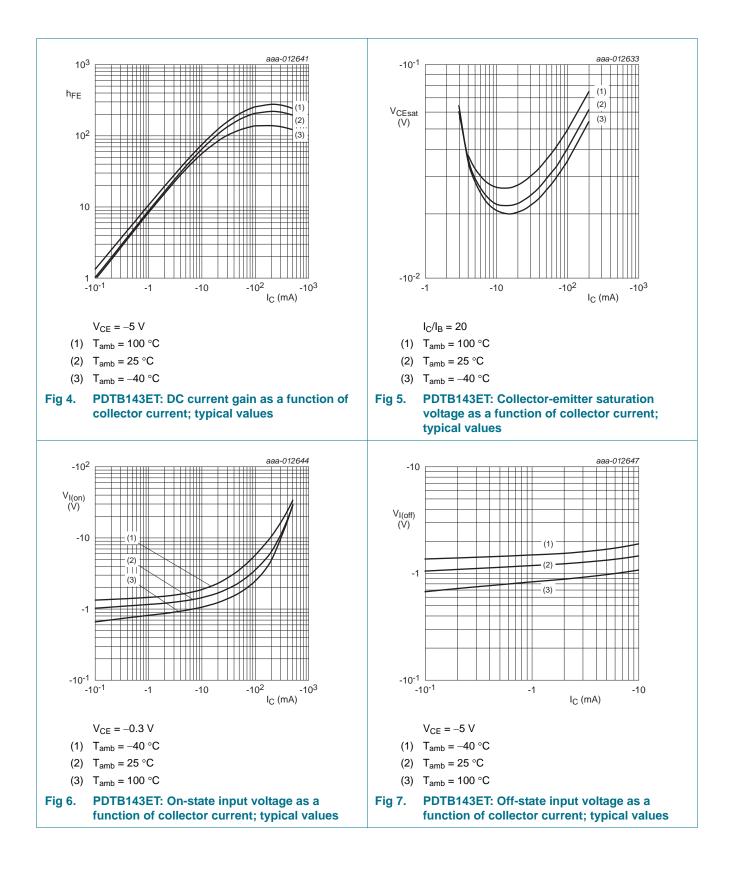
## 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = -40 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	-	-100	nA
	current	V <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = -50 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	-	-0.5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$				
	PDTB143ET		-	-	-0.9	mA
	PDTB143XT		-	-	-0.6	mA
	PDTB114ET		-	-	-0.4	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -50 \text{ mA}$				
	PDTB143ET		60	-	-	
	PDTB143XT		70	-	-	
	PDTB114ET		70	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = -50 \text{ mA};$ $I_{B} = -2.5 \text{ mA}$	-	-	-100	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -100 \mu\text{A}$				-
	PDTB143ET		-0.6	-0.9	-1.5	V
	PDTB143XT		-0.5	-0.75	-1.1	V
	PDTB114ET		-0.6	-1.0	-1.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = -0.3 \text{ V}; I_C = -20 \text{ mA}$				
	PDTB143ET		-1.0	-1.7	-2.2	V
	PDTB143XT		-1.0	-1.4	-2.0	V
	PDTB114ET		-1.0	-2.2	-3.0	V
R1	bias resistor 1 (input)					
	PDTB143ET		3.3	4.7	6.1	kΩ
	PDTB143XT		3.3	4.7	6.1	kΩ
	PDTB114ET		7.0	10	13	kΩ
R2/R1	bias resistor ratio					
	PDTB143ET		0.9	1.0	1.1	
	PDTB143XT		1.91	2.13	2.34	
	PDTB114ET		0.9	1.0	1.1	
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 1 MHz	-	11	-	pF
f <sub>T</sub>	transition frequency	$V_{CE} = -5 V;$ [1] $I_C = -50 mA;$ f = 100 MHz	-	140	-	MHz

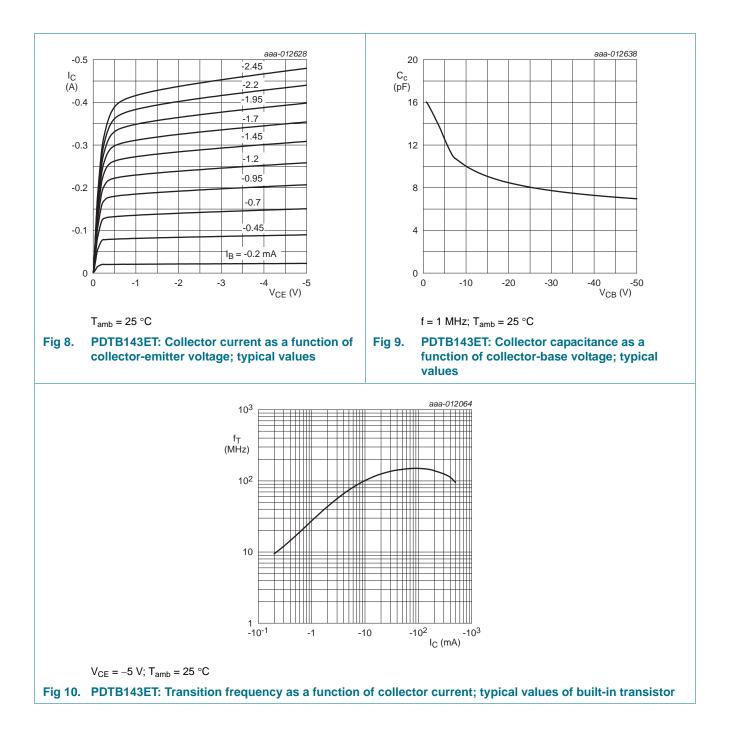
Table 8. Characteristics

[1] Characteristics of built-in transistor.

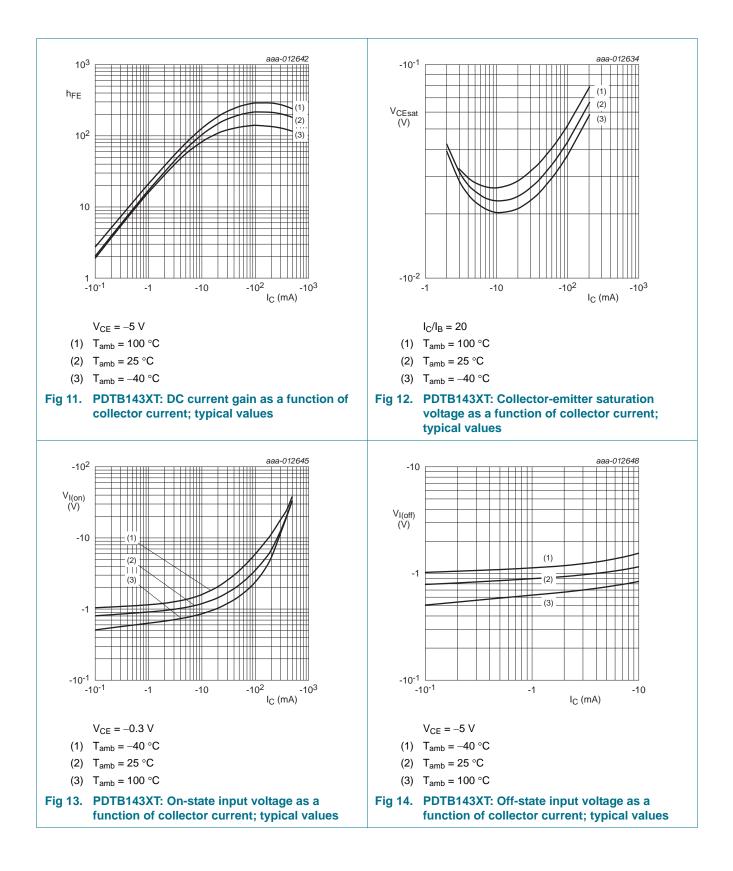
## **PDTB1xxxT series**



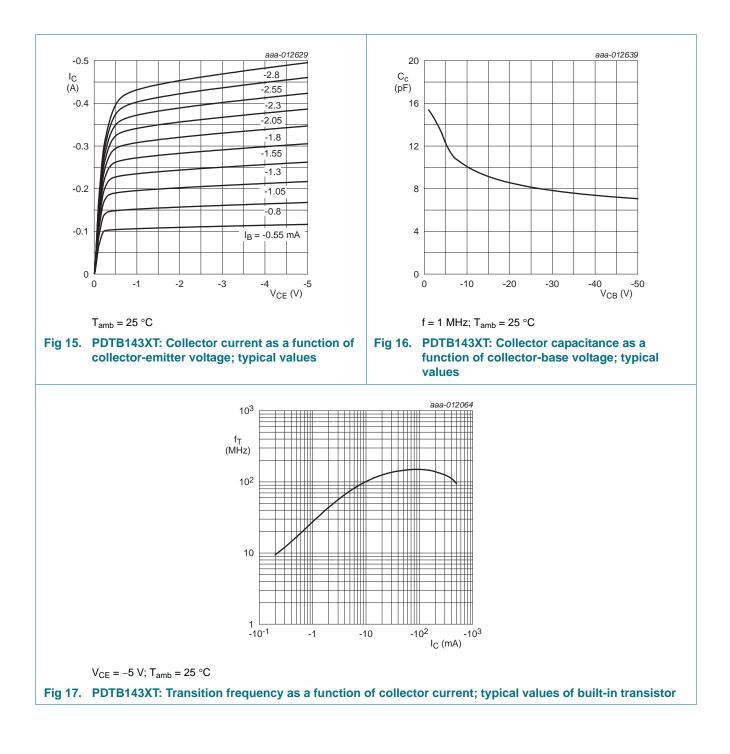
# PDTB1xxxT series



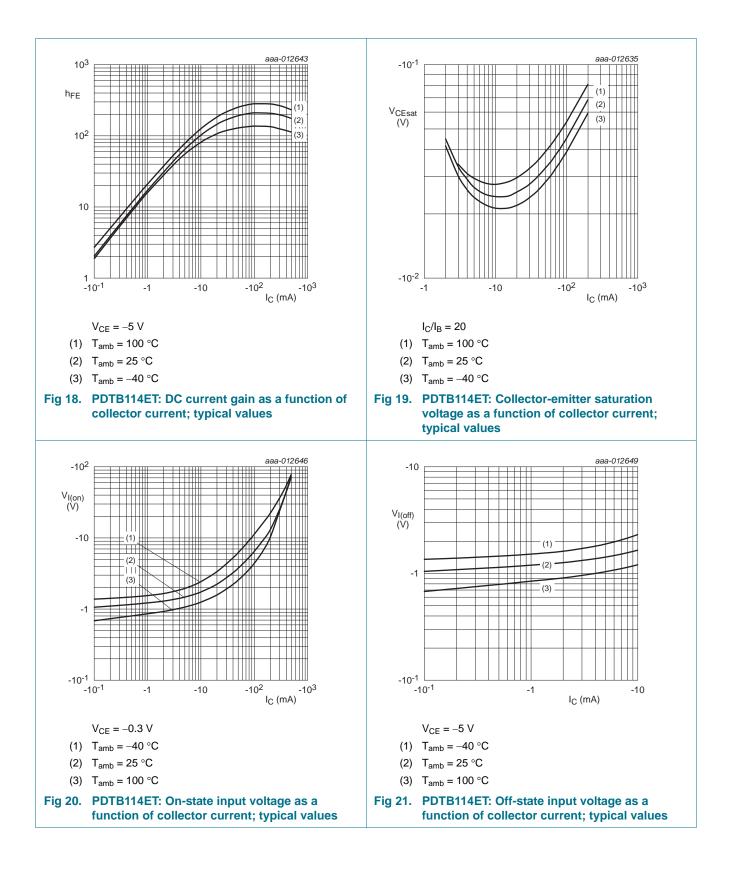
## **PDTB1xxxT series**



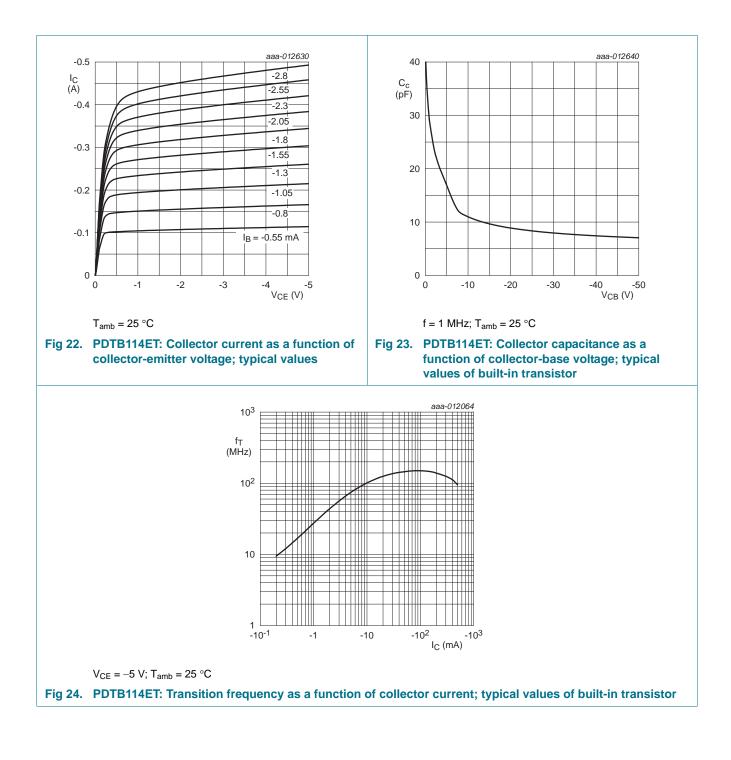
# PDTB1xxxT series



## **PDTB1xxxT series**



# PDTB1xxxT series



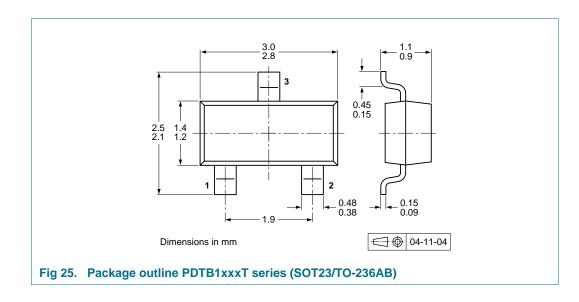
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### 8. Test information

### 8.1 Quality information

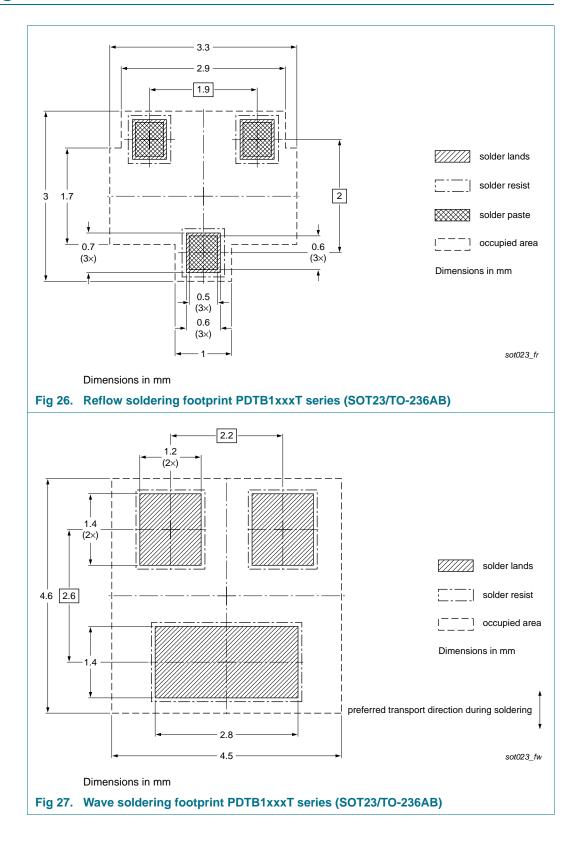
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



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### **10. Soldering**



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## **11. Revision history**

Table 9. Revision history
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Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTB1XXXT_SER v.1	20140513	Product data sheet	-	-

500 mA, 50 V PNP resistor-equipped transistors

### **12. Legal information**

#### 12.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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